## NSN 5961-01-042-5479

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-042-5479 **Inclosure Material:** Metal **Overall Length:** Between 0.065 inches and 0.085 inches Overall Diameter: Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 40.0 breakdown voltage, collector-to-emitter, base open and 60.0 breakdown voltage, collector to emitter, with specified voltage between base and emitter and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 700.00 milliamperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5879 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: